



# <u>MMDT5401</u>

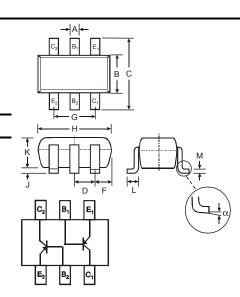
DUAL PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMDT5551)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

#### Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4M, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



	SOT-363							
Dim	Dim Min Max							
Α	0.10	0.30						
В	1.15	1.35						
С	2.00	2.20						
D	0.65 N	ominal						
F	0.30	0.40						
н	1.80	2.20						
J		0.10						
Κ	0.90	1.00						
L	0.25	0.40						
м	0.10	0.25						
α	0°	8°						
All Dir	nensions	in mm						

### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

			F	r
Characteristic		Symbol	Value	Unit
Collector-Base Voltage		V <sub>CBO</sub>	-160	V
Collector-Emitter Voltage		V <sub>CEO</sub>	-150	V
Emitter-Base Voltage		V <sub>EBO</sub>	-5.0	V
Collector Current – Continuous	(Note 1)	lc	-200	mA
Power Dissipation	(Note 1,2)	Pd	200	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ ext{ heta}JA}$	625	°C/W
Operating and Storage and Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. Maximum combined dissipation.

3. No purposefully added lead.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

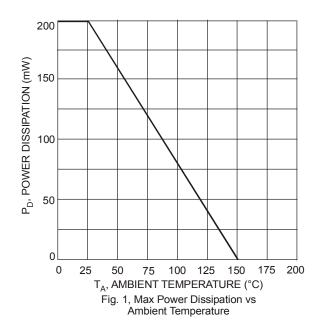


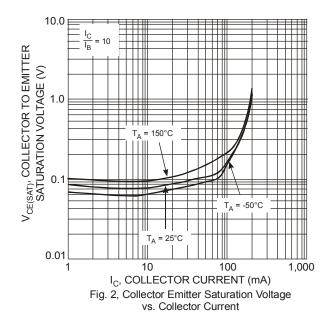
**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-160	_	V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-150	_	V	$I_{\rm C}$ = -1.0mA, $I_{\rm B}$ = 0
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-5.0	_	V	$I_{\rm E}$ = -10µA, $I_{\rm C}$ = 0
Collector Cutoff Current	I <sub>CBO</sub>	_	-50	nA μA	V <sub>CB</sub> = -120V, I <sub>E</sub> = 0 V <sub>CB</sub> = -120V, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C
Emitter Cutoff Current	I <sub>EBO</sub>	_	-50	nA	$V_{EB} = -3.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 6)					
DC Current Gain	h <sub>FE</sub>	50 60 50	 240 	_	$I_{C} = -1.0mA, V_{CE} = -5.0V$ $I_{C} = -10mA, V_{CE} = -5.0V$ $I_{C} = -50mA, V_{CE} = -5.0V$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-0.2 -0.5	v	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	-1.0	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C <sub>obo</sub>	_	6.0	pF	V <sub>CB</sub> = -10V, f = 1.0MHz, I <sub>E</sub> = 0
Small Signal Current Gain	h <sub>fe</sub>	40	200		V <sub>CE</sub> = -10V, I <sub>C</sub> = -1.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f <sub>T</sub>	100	300	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -10mA, f = 100MHz
Noise Figure	NF	_	8.0	dB	$V_{CE}$ = -5.0V, I <sub>C</sub> = -200µA, R <sub>S</sub> = 10Ω, f = 1.0kHz

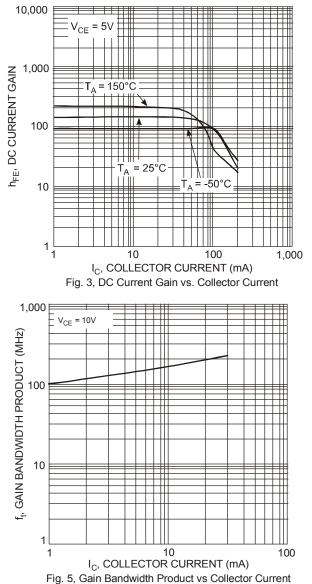
Notes:

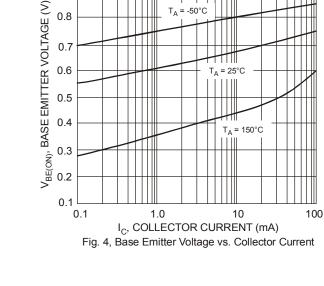
6. Short duration pulse test used to minimize self-heating effect.











T<sub>A</sub> = -50°C

1.0

0.9

0.8

0.7

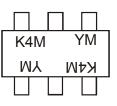
 $V_{CE} = 5V$ 

#### Ordering Information (Note 7)

Device	Packaging	Shipping
MMDT5401-7-F	SOT-363	3000/Tape & Reel

7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

## **Marking Information**



K4M = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Data Code Key															
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	К	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z

Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



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